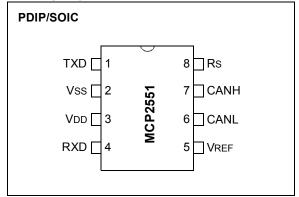


# **High-Speed CAN Transceiver**

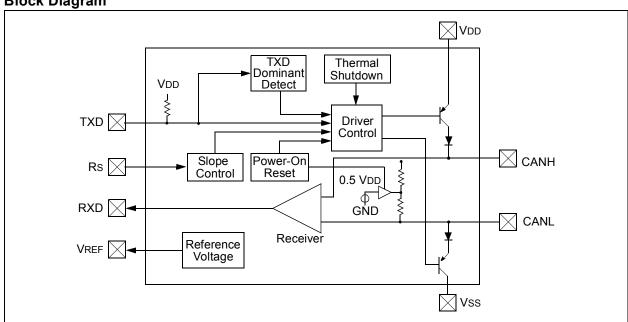
# **Features**

- · Supports 1 Mb/s operation
- Implements ISO-11898 standard physical layer requirements
- · Suitable for 12V and 24V systems
- Externally-controlled slope for reduced RFI emissions
- Detection of ground fault (permanent dominant) on TXD input
- · Power-on reset and voltage brown-out protection
- An unpowered node or brown-out event will not disturb the CAN bus
- · Low current standby operation
- Protection against damage due to short-circuit conditions (positive or negative battery voltage)
- · Protection against high-voltage transients
- · Automatic thermal shutdown protection
- Up to 112 nodes can be connected
- High noise immunity due to differential bus implementation
- · Temperature ranges:
  - Industrial (I): -40°C to +85°C
  - Extended (E): -40°C to +125°C

# **Package Types**



# **Block Diagram**



NOTES:

# 1.0 DEVICE OVERVIEW

The MCP2551 is a high-speed CAN, fault-tolerant device that serves as the interface between a CAN protocol controller and the physical bus. The MCP2551 provides differential transmit and receive capability for the CAN protocol controller and is fully compatible with the ISO-11898 standard, including 24V requirements. It will operate at speeds of up to 1 Mb/s.

Typically, each node in a CAN system must have a device to convert the digital signals generated by a CAN controller to signals suitable for transmission over the bus cabling (differential output). It also provides a buffer between the CAN controller and the high-voltage spikes that can be generated on the CAN bus by outside sources (EMI, ESD, electrical transients, etc.).

#### 1.1 Transmitter Function

The CAN bus has two states: Dominant and Recessive. A dominant state occurs when the differential voltage between CANH and CANL is greater than a defined voltage (e.g.,1.2V). A recessive state occurs when the differential voltage is less than a defined voltage (typically 0V). The dominant and recessive states correspond to the low and high state of the TXD input pin, respectively. However, a dominant state initiated by another CAN node will override a recessive state on the CAN bus.

# 1.1.1 MAXIMUM NUMBER OF NODES

The MCP2551 CAN outputs will drive a minimum load of  $45\Omega$ , allowing a maximum of 112 nodes to be connected (given a minimum differential input resistance of  $20~\text{k}\Omega$  and a nominal termination resistor value of  $120\Omega$ ).

# 1.2 Receiver Function

The RXD output pin reflects the differential bus voltage between CANH and CANL. The low and high states of the RXD output pin correspond to the Dominant and Recessive states of the CAN bus, respectively.

### 1.3 Internal Protection

CANH and CANL are protected against battery short-circuits and electrical transients that can occur on the CAN bus. This feature prevents destruction of the transmitter output stage during such a fault condition.

The device is further protected from excessive current loading by thermal shutdown circuitry that disables the output drivers when the junction temperature exceeds a nominal limit of 165°C. All other parts of the chip remain operational and the chip temperature is lowered due to the decreased power dissipation in the transmitter outputs. This protection is essential to protect against bus line short-circuit induced damage.

# 1.4 Operating Modes

The Rs pin allows three modes of operation to be selected:

- · High-Speed
- · Slope-Control
- Standby

These modes are summarized in Table 1-1.

When in High-Speed or Slope-Control mode, the drivers for the CANH and CANL signals are internally regulated to provide controlled symmetry in order to minimize EMI emissions.

Additionally, the slope of the signal transitions on CANH and CANL can be controlled with a resistor connected from pin 8 (Rs) to ground, with the slope proportional to the current output at Rs, further reducing EMI emissions.

### 1.4.1 HIGH-SPEED

The High-Speed mode is selected by connecting the Rs pin to Vss. In this mode, the transmitter output drivers have fast output rise and fall times to support high-speed CAN bus rates.

### 1.4.2 SLOPE-CONTROL

Slope-Control mode further reduces EMI by limiting the rise and fall times of CANH and CANL. The slope, or slew rate (SR), is controlled by connecting an external resistor (REXT) between Rs and Vol (usually ground). The slope is proportional to the current output at the Rs pin. Since the current is primarily determined by the slope-control resistance value REXT, a certain slew rate is achieved by applying a respective resistance. Figure 1-1 illustrates typical slew rate values as a function of the slope-control resistance value.

# 1.4.3 STANDBY MODE

The device may be placed in standby or "SLEEP" mode by applying a high-level to Rs. In SLEEP mode, the transmitter is switched off and the receiver operates at a lower current. The receive pin on the controller side (RXD) is still functional but will operate at a slower rate. The attached microcontroller can monitor RXD for CAN bus activity and place the transceiver into normal operation via the Rs pin (at higher bus rates the first CAN message may be lost).

TABLE 1-1: MODES OF OPERATION

Mode	Current at R <sub>s</sub> Pin	Resulting Voltage at Rs Pin
Standby	-lrs < 10 μA	VRS > 0.75VDD
Slope-Control	10 μA < -IRS < 200 μA	0.4VDD < VRS < 0.6VDD
High-Speed	-IRS < 610 μA	0 < VRS < 0.3VDD

TABLE 1-2: TRANSCEIVER TRUTH TABLE

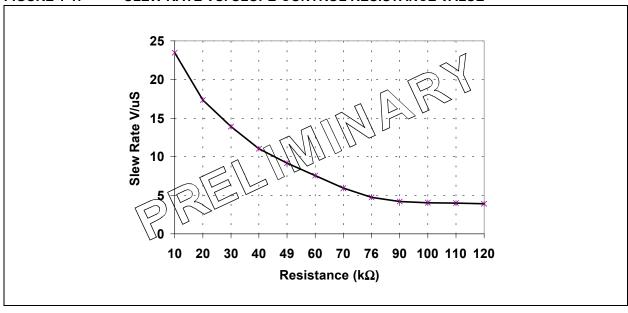
VDD	VRS	TXD	CANH	CANL	Bus State <sup>(1)</sup>	Rxd <sup>(1)</sup>
4.5V ≤ VDD ≤ 5.5V	VRS < 0.75VDD	0	HIGH	LOW	Dominant	0
		1 or floating	Not Driven	Not Driven	Recessive	1
	VRS > 0.75VDD	Х	Not Driven	Not Driven	Recessive	1
VPOR < VDD < 4.5V	VRS < 0.75VDD	0	HIGH	LOW	Dominant	0
(See Note 3)		1 or floating	Not Driven	Not Driven	Recessive	1
	VRS > 0.75VDD	X	Not Driven	Not Driven	Recessive	1
0 < VDD < VPOR	Х	Х	Not Driven/	Not Driven/	High Impedance	Х
			No Load	No Load		

Note 1: If another bus node is transmitting a dominant bit on the CAN bus, then RXD is a logic 0.

2: X = "don't care".

3: Device drivers will function, although outputs are not guaranteed to meet the ISO-11898 specification.

FIGURE 1-1: SLEW RATE VS. SLOPE-CONTROL RESISTANCE VALUE



# 1.5 TXD Permanent Dominant Detection

If the MCP2551 detects an extended low state on the TXD input, it will disable the CANH and CANL output drivers in order to prevent the corruption of data on the CAN bus. The drivers are disabled if TXD is low for more than 1.25 ms (minimum). This implies a maximum bit time of 62.5 µs (16 kb/s bus rate) allowing up to 20 consecutive transmitted dominant bits during a multiple bit error and error frame scenario. The drivers remain disabled as long as TXD remains low. A rising edge on TXD will reset the timer logic and enable the CANH and CANL output drivers.

# 1.6 Power-on Reset

When the device is powered on, CANH and CANL remain in a high-impedance state until VDD reaches the voltage level VPORH. In addition, CANH and CANL will remain in a high-impedance state if TXD is low when VDD reaches VPORH. CANH and CANL will become active only after TXD is asserted high. Once powered on, CANH and CANL will enter a high-impedance state if the voltage level at VDD falls below VPORL, providing voltage brown-out protection during normal operation.

# 1.7 Pin Descriptions

The 8-pin pinout is listed in Table 1-3.

TABLE 1-3: MCP2551 PINOUT

Pin Number	Pin Name	Pin Function
1	TXD	Transmit Data Input
2	Vss	Ground
3	Vdd	Supply Voltage
4	RXD	Receive Data Output
5	VREF	Reference Output Voltage
6	CANL	CAN Low-Level Voltage I/O
7	CANH	CAN High-Level Voltage I/O
8	Rs	Slope-Control Input

# 1.7.1 TRANSMITTER DATA INPUT (TXD)

TXD is a TTL compatible input pin. The data on this pin is driven out on the CANH and CANL differential output pins. It is usually connected to the transmitter data output of the CAN controller device. When TXD is low, CANH and CANL are in the dominant state. When TXD is high, CANH and CANL are in the recessive state, provided that another CAN node is not driving the CAN bus with a dominant state. TXD has an internal pull-up resistor (nominal 25  $k\Omega$  to VDD).

# 1.7.2 GROUND SUPPLY (Vss)

Ground supply pin.

# 1.7.3 SUPPLY VOLTAGE (VDD)

Positive supply voltage pin.

# 1.7.4 RECEIVER DATA OUTPUT (RXD)

RXD is a CMOS-compatible output that drives high or low depending upon the differential signals on the CANH and CANL pins and is usually connected to the receiver data input of the CAN controller device. RXD is high when the CAN bus is recessive and low in the dominant state.

# 1.7.5 REFERENCE VOLTAGE (VREF)

Reference Voltage Output (Defined as VDD/2).

# 1.7.6 CAN LOW (CANL)

The CANL output drives the low side of the CAN differential bus. This pin is also tied internally to the receive input comparator.

# 1.7.7 CAN HIGH (CANH)

The CANH output drives the high side of the CAN differential bus. This pin is also tied internally to the receive input comparator.

# 1.7.8 SLOPE RESISTOR INPUT (Rs)

The Rs pin is used to select High-Speed, Slope-Control or Standby modes via an external biasing resistor.

# 2.0 ELECTRICAL CHARACTERISTICS

# 2.1 Terms and Definitions

A number of terms are defined in ISO-11898 that are used to describe the electrical characteristics of a CAN transceiver device. These terms and definitions are summarized in this section.

# 2.1.1 BUS VOLTAGE

VCANL and VCANH, denoting the voltages of the bus line wires, CANL and CANH, relative to ground of each individual CAN node.

# 2.1.2 COMMON MODE BUS VOLTAGE RANGE

Boundary voltage levels of VCANL and VCANH with respect to ground, for which proper operation will occur, if up to the maximum number of CAN nodes are connected to the bus.

# 2.1.3 DIFFERENTIAL INTERNAL CAPACITANCE, CDIFF (OF A CAN NODE)

Capacitance seen between CANL and CANH during the recessive state when the CAN node is disconnected from the bus (see Figure 2-1).

# 2.1.4 DIFFERENTIAL INTERNAL RESISTANCE, RDIFF (OF A CAN NODE)

Resistance seen between CANL and CANH during the recessive state when the CAN node is disconnected from the bus (see Figure 2-1).

# 2.1.5 DIFFERENTIAL VOLTAGE, VDIFF (OF CAN BUS)

Differential voltage of the two-wire CAN bus, value VDIFF = VCANH - VCANL.

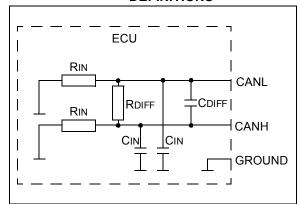
# 2.1.6 INTERNAL CAPACITANCE, CIN (OF A CAN NODE)

Capacitance seen between CANL (or CANH) and ground during the recessive state when the CAN node is disconnected from the bus (see Figure 2-1).

# 2.1.7 INTERNAL RESISTANCE, RIN (OF A CAN NODE)

Resistance seen between CANL (or CANH) and ground during the recessive state when the CAN node is disconnected from the bus (see Figure 2-1).

FIGURE 2-1: PHYSICAL LAYER DEFINITIONS



# **Absolute Maximum Ratings†**

VDD	7.0\
DC Voltage at TXD, RXD, VREF and Vs	0.3V to VDD + 0.3\
DC Voltage at CANH, CANL (Note 1)	42V to +42\
Transient Voltage on Pins 6 and 7 (Note 2)	250V to +250\
Storage temperature	55°C to +150°C
Operating ambient temperature	40°C to +125°C
Virtual Junction Temperature, TvJ (Note 3)	40°C to +150°C
Soldering temperature of leads (10 seconds)	+300°C
ESD protection on CANH and CANL pins (Note 4)	6 k\
ESD protection on all other pins (Note 4)	4 k\

- Note 1: Short-circuit applied when TXD is high and low.
  - 2: In accordance with ISO-7637.
  - 3: In accordance with IEC 60747-1.
  - 4: Classification A: Human Body Model.

† NOTICE: Stresses above those listed under "Maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# 2.2 DC Characteristics

DC Spec	ifications		Industrial (	•	°C to +8	5°C VDD = 4.5V to 5.5V 125°C VDD = 4.5V to 5.5V
Param No.	Sym	Characteristic	Min	Max	Units	Conditions
Supply:						
D1	IDD	Supply Current	_	75	mA	Dominant; VTXD = 0.8V; VDD
D2			_	10	mA	Recessive; $VTXD = +2V$ ; $Rs = 47 \text{ k}\Omega$
D3			1	365	μΑ	$-40^{\circ}\text{C} \le \text{T}_{\text{AMB}} \le +85^{\circ}\text{C},$ Standby; <b>(Note 2)</b>
			1	465	μΑ	$-40^{\circ}\text{C} \le \text{T}_{\text{AMB}} \le +125^{\circ}\text{C},$ Standby; <b>(Note 2)</b>
D4	VPORH	High-level of the power-on reset comparator	3.8	4.3	V	CANH, CANL outputs are active when VDD > VPORH
D5	VPORL	Low-level of the power-on reset comparator	3.4	4.0	V	CANH, CANL outputs are not active when VDD < VPORL
D6	VPORD	Hysteresis of power-on reset comparator	0.3	0.8	V	Note 1
3us Line	(CANH; CANL) Tra	nsmitter:				
D7	$VCANH_{(r)}$ ; $VCANL_{(r)}$	CANH, CANL Recessive bus voltage	2.0	3.0	V	VTXD = VDD; no load.
D8	IO(CANH)(reces) IO(CANL)(reces)	Recessive output current	-2	+2	mA	-2V < V(CAHL,CANH) < +7V, 0V <vdd 5.5v<="" <="" td=""></vdd>
D9			-10	+10	mA	-5V < V(CANL,CANH) < +40V, 0V <vdd 5.5v<="" <="" td=""></vdd>
D10	Vo(canh)	CANH dominant output voltage	2.75	4.5	V	VTXD = 0.8V
D11	Vo(canl)	CANL dominant output voltage	0.5	2.25	V	VTXD = 0.8V
D12	VDIFF(r)(o)	Recessive differential output voltage	-500	+50	mV	VTXD = 2V; no load
D13	VDIFF(d)(o)	Dominant differential output voltage	1.5	3.0	V	VTXD = 0.8V; VDD = 5V 40 Ω < RL < 60 Ω (Note 2)
D14	Io(SC)(canh)	CANH short-circuit output		-200	mA	VCANH = -5V
D15		current		-100 (typical)	mA	VCANH = -40V, +40V. (Note 1)
D16	Io(SC)(CANL)I	CANL short circuit output current		200	mA	VCANL = -40V, +40V. (Note 1)
3us Line	(CANH; CANL) Re	ceiver: [TXD = 2V; pins 6 and 7 e	xternally di	riven]		
D17	VDIFF(r)(i)	Recessive differential input voltage	-1.0	+0.5	V	-2V < V(CANL, CANH) < +7V (Note 3)
			-1.0	+0.4	V	-12V < V(CANL, CANH) < +12V (Note 3)
D18	VDIFF(d)(i)	Dominant differential input voltage	0.9	5.0	V	-2V < V(CANL, CANH) < +7V (Note 3)
			1.0	5.0	V	-12V < V(CANL, CANH) < +12V (Note 3)
D19	VDIFF(h)(i)	Differential input hysteresis	100	200	mV	see Figure 2-4. (Note 1)
D20	Rin	CANH, CANL common-mode input resistance	5	50	kΩ	
D21	Rın(d)	Deviation between CANH and CANL common-mode input resistance	-3	+3	%	VCANH = VCANL

Note 1: This parameter is periodically sampled and not 100% tested.

- 2: ITXD = IRXD = IVREF = 0 mA; 0V < VCANL < VDD; 0V < VCANH < VDD; VRS = VDD
- 3: This is valid for the receiver in all modes, High-Speed, Slope-Control and standby.

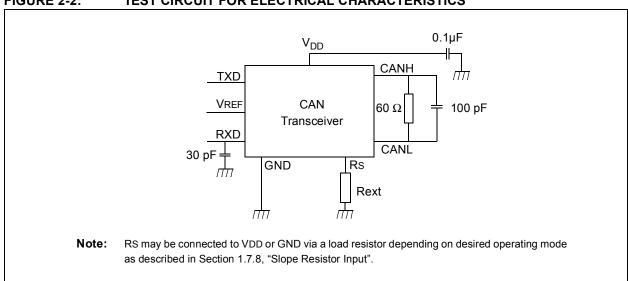
# 2.2 DC Characteristics (Continued)

DC Specifications (Continued)			Electrical Characteristics: Industrial (I): TAMB = -40°C to +85°C VDD = 4.5V to 5.5V Extended (E): TAMB = -40°C to +125°C VDD = 4.5V to 5.5V				
Param No.	Sym	Characteristic	Min	Max	Units	Conditions	
Bus Line (	CANH; CANL) F	Receiver: [TXD = 2V; pins 6 and 7 e	externally dri	ven]			
D22	Rdiff	Differential input resistance	20	100	kΩ		
D24	lli	CANH, CANL input leakage current	_	150	μΑ	VDD < VPOR; VCANH = VCANL = +5V	
Transmitte	r Data Input (T)	KD):		•	•		
D25	VIH	High-level input voltage	2.0	_	V	Output recessive	
D26	VIL	Low-level input voltage	_	+0.8	V	Output dominant	
D27	liн	High-level input current	-1	+1	μA	VTXD = VDD	
D28	lıL	Low-level input current	-100	-400	μA	VTXD = 0V	
Receiver D	ata Output (RX	D):	•	-		•	
D31	Voн	High-level output voltage	0.7	_	V	Iон = 8 mA	
D32	Vol	Low-level output voltage	_	0.8	V	IOL = 8 mA	
Voltage Re	ference Output	(VREF):					
D33	VREF	Reference output voltage	0.45 Vdd	0.55 VDD	V	-50 μA < IVREF < 50 μA	
Standby/S	lope-Control (R	s pin):					
D34	Vstb	Input voltage for standby mode	0.75 Vdd	_	V		
D35	ISLOPE	Slope-control mode current	-10	-200	μΑ		
D36	VSLOPE	Slope-control mode voltage	0.4 VDD	0.6 Vdd	V		
Thermal SI	hutdown:						
D37	T <sub>J(sd)</sub>	Shutdown junction temperature	155	180	°C	Note 1	
D38	TJ <sub>(h)</sub>	Shutdown temperature hysteresis	20	30	°C	-12V < V(CANL, CANH) < +12V (Note 3)	

Note 1: This parameter is periodically sampled and not 100% tested.

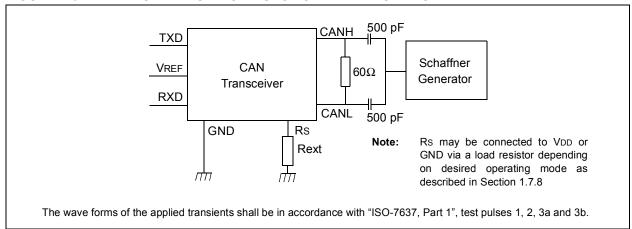
- 2: ITXD = IRXD = IVREF = 0 mA; 0V < VCANL < VDD; 0V < VCANH < VDD; VRS = VDD
- 3: This is valid for the receiver in all modes, High-Speed, Slope-Control and standby.

# FIGURE 2-2: TEST CIRCUIT FOR ELECTRICAL CHARACTERISTICS

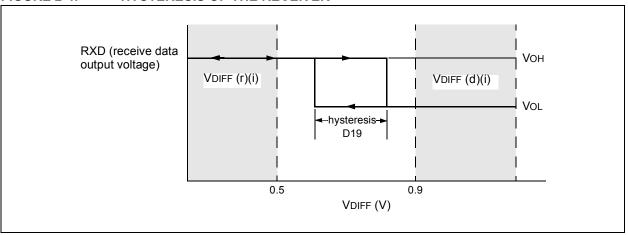


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# FIGURE 2-3: TEST CIRCUIT FOR AUTOMOTIVE TRANSIENTS



# FIGURE 2-4: HYSTERESIS OF THE RECEIVER



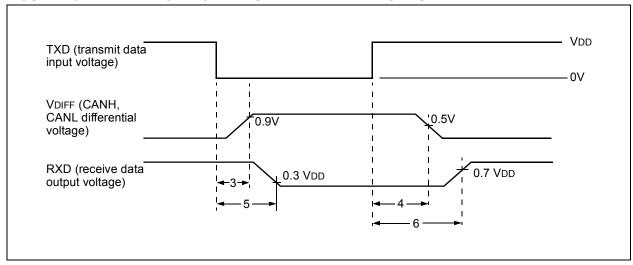
# 2.3 AC Characteristics

AC Specifications			Electrical Characteristics: Industrial (I): TAMB = -40°C to +85°CVDD = 4.5V to 5.5V Extended (E): TAMB = -40°C to +125°CVDD = 4.5V to 5.5V				
Param No.	Sym	Characteristic	Min	Max	Units	Conditions	
1	tвіт	Bit time	1	62.5	μs	VRS = 0V	
2	fвіт	Bit frequency	16	1000	kHz	VRS = 0V	
3	TtxL2bus(d)	Delay TXD to bus active	_	70	ns	-40°C ≤ TAMB ≤ +125°C, VRS = 0V	
4	TtxH2bus(r)	Delay TXD to bus inactive	_	125	ns	-40°C ≤ TAMB ≤ +85°C, VRS = 0V	
			_	170	ns	-40°C ≤ TAMB ≤ +125°C, VRS = 0V	
5	TtxL2rx(d)	Delay TXD to receive active	_	130	ns	-40°C ≤ TAMB ≤ +125°C, VRS = 0V	
			_	250	ns	$-40^{\circ}\text{C} \le \text{TAMB} \le +125^{\circ}\text{C},$ Rs = 47 k $\Omega$	
6	TtxH2rx(r)	Delay TXD to receiver inactive	_	175	ns	$-40^{\circ}\text{C} \le \text{TAMB} \le +85^{\circ}\text{C},$ VRS = 0V	
			_	225	ns	$-40^{\circ}\text{C} \le \text{TAMB} \le +85^{\circ}\text{C},$ Rs = 47 k $\Omega$	
			_	235	ns	-40°C ≤ TAMB ≤ +125°C, VRS = 0V	
			_	400	ns	$-40^{\circ}\text{C} \le \text{TAMB} \le +125^{\circ}\text{C},$ Rs = 47 k $\Omega$	
7	SR	CANH, CANL slew rate	5.5	8.5	V/µs	Refer to Figure 1-1; Rs = 47 k $\Omega$ , ( <b>Note 1</b> )	
10	twake	Wake-up time from standby (Rs pin)	_	5	μs	see Figure 2-6	
11	TbusD2rx(s)	Bus dominant to RXD Low (standby mode)	_	550	ns	VRS = +4V; (see <b>Figure 2-7</b> )	
12	CIN(CANH) CIN(CANL)	CANH; CANL input capacitance	_	20 (typical)	pF	1 Mbit/s data rate; VTXD = VDD, (Note 1)	
13	CDIFF	Differential input capacitance	_	10 (typical)	pF	1 Mbit/s data rate (Note 1)	
14	TtxL2busZ	TX Permanent Dominant Timer Disable Time	1.25	4	ms		
15	TtxR2pdt(res)	TX Permanent Dominant Timer Reset Time	_	1	μs	Rising edge on TXD while device is in permanent dominant state	

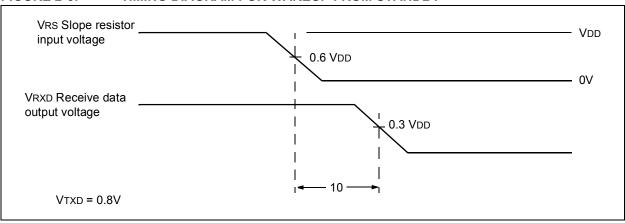
Note 1: This parameter is periodically sampled and not 100% tested.

# 2.4 Timing Diagrams and Specifications

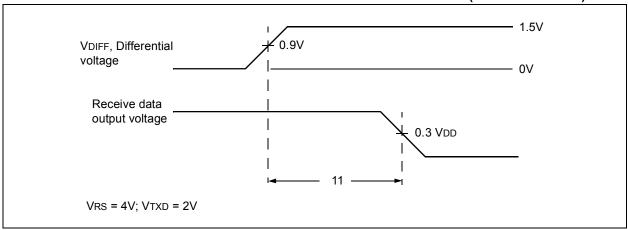
# FIGURE 2-5: TIMING DIAGRAM FOR AC CHARACTERISTICS



# FIGURE 2-6: TIMING DIAGRAM FOR WAKEUP FROM STANDBY



# FIGURE 2-7: TIMING DIAGRAM FOR BUS DOMINANT TO RXD LOW (STANDBY MODE)

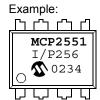


# 3.0 PACKAGING INFORMATION

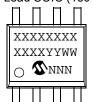
# 3.1 Package Marking Information

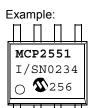












**Legend:** XX...X Customer specific information\*

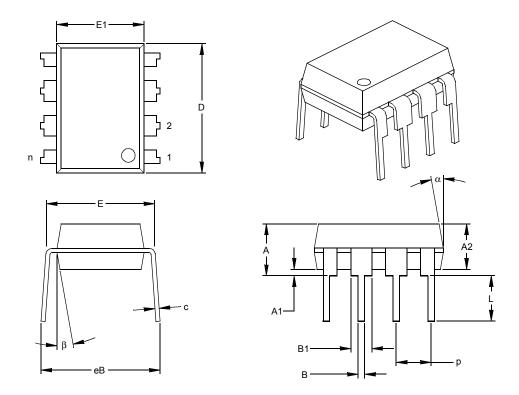
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

**Note**: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

\* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

# 8-Lead Plastic Dual In-line (P) - 300 mil (PDIP)



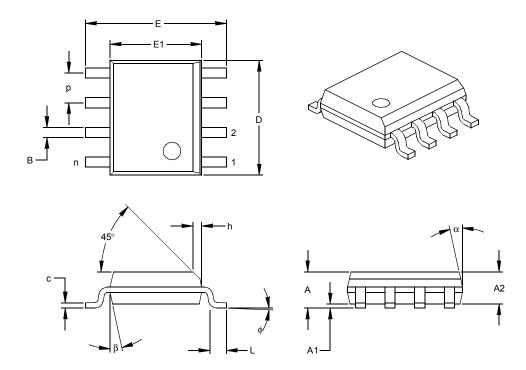
	INCHES*			MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing §	eВ	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-001
Drawing No. C04-018

<sup>\*</sup> Controlling Parameter § Significant Characteristic

# 8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)



Units		INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.
JEDEC Equivalent: MS-012
Drawing No. C04-057

<sup>\*</sup> Controlling Parameter § Significant Characteristic

NOTES:

# PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	X /XX	Examples:
Device	Temperature Package Range	MCP2551-I/P: Industrial temperature,     PDIP package.
Device:	MCP2551= High-Speed CAN Transceiver	b) MCP2551-E/P: Extended temperature, PDIP package. c) MCP2551-I/SN: Industrial temperature, SOIC package.
Temperature Range:	I = -40°C to +85°C E = -40°C to +125°C	d) MCP2551T-I/SN: Tape and Reel, Industrial Temperature, SOIC package. e) MCP2551T-E/SN: Tape and Reel, Extended Temperature, SOIC package.
Package:	P = Plastic DIP (300 mil Body) 8-lead SN = Plastic SOIC (150 mil Body) 8-lead	Extended remperature, 3010 package.

# **Sales and Support**

# **Data Sheets**

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
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Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

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NOTES:

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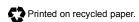
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2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: 480-792-7627 Web Address: http://www.microchip.com

#### **Rocky Mountain**

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7966 Fax: 480-792-4338

# **Atlanta**

3780 Mansell Road, Suite 130 Alpharetta, GA 30022 Tel: 770-640-0034 Fax: 770-640-0307

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Tel: 978-692-3848 Fax: 978-692-3821

# Chicago

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Tel: 630-285-0071 Fax: 630-285-0075

4570 Westgrove Drive, Suite 160 Addison, TX 75001 Tel: 972-818-7423 Fax: 972-818-2924

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Tri-Atria Office Building 32255 Northwestern Highway, Suite 190 Farmington Hills, MI 48334 Tel: 248-538-2250 Fax: 248-538-2260

#### Kokomo

2767 S. Albright Road Kokomo, Indiana 46902 Tel: 765-864-8360 Fax: 765-864-8387

### Los Angeles

18201 Von Karman, Suite 1090 Irvine, CA 92612 Tel: 949-263-1888 Fax: 949-263-1338

# San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408-436-7950 Fax: 408-436-7955

#### Toronto

6285 Northam Drive, Suite 108 Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699 Fax: 905-673-6509

### ASIA/PACIFIC

#### Australia

Microchip Technology Australia Pty Ltd Suite 22, 41 Rawson Street Epping 2121, NSW Australia

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

#### China - Beijing

Microchip Technology Consulting (Shanghai) Co., Ltd., Beijing Liaison Office Bei Hai Wan Tai Bldg.

No. 6 Chaoyangmen Beidajie Beijing, 100027, No. China Tel: 86-10-85282100 Fax: 86-10-85282104

China - Chengdu

Microchip Technology Consulting (Shanghai)
Co., Ltd., Chengdu Liaison Office
Rm. 2401-2402, 24th Floor,
Ming Xing Financial Tower No. 88 TIDU Street Chengdu 610016, China Tel: 86-28-86766200 Fax: 86-28-86766599

#### China - Fuzhou

Microchip Technology Consulting (Shanghai) Co., Ltd., Fuzhou Liaison Office Unit 28F, World Trade Plaza No. 71 Wusi Road Fuzhou 350001, China Tel: 86-591-7503506 Fax: 86-591-7503521

### China - Shanghai

Microchip Technology Consulting (Shanghai) Co., Ltd. Room 701, Bldg. B Far East International Plaza No. 317 Xian Xia Road Shanghai, 200051 Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

# China - Shenzhen

Microchip Technology Consulting (Shanghai) Co., Ltd., Shenzhen Liaison Office Rm. 15-16, 13/F, Shenzhen Kerry Centre, Renminnan Lu

Shenzhen 518001, China Tel: 86-755-82350361 Fax: 86-755-82366086

# China - Hong Kong SAR

Microchip Technology Hongkong Ltd. Unit 901-6, Tower 2, Metroplaza 223 Hing Fong Road Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

#### India

Microchip Technology Inc. India Liaison Office Divyasree Chambers 1 Floor, Wing A (A3/A4) No. 11, O'Shaugnessey Road Bangalore, 560 025, India Tel: 91-80-2290061 Fax: 91-80-2290062

#### Japan

Microchip Technology Japan K.K. Benex S-1 6F 3-18-20, Shinyokohama Kohoku-Ku, Yokohama-shi Kanagawa, 222-0033, Japan Tel: 81-45-471-6166 Fax: 81-45-471-6122

#### Korea

Microchip Technology Korea 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882

Tel: 82-2-554-7200 Fax: 82-2-558-5934

### Singapore

Microchip Technology Singapore Pte Ltd. 200 Middle Road #07-02 Prime Centre Singapore, 188980 Tel: 65-6334-8870 Fax: 65-6334-8850

#### Taiwan

Microchip Technology (Barbados) Inc., Taiwan Branch 11F-3, No. 207 Tung Hua North Road Taipei, 105, Taiwan Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

### **EUROPE**

#### Austria

Microchip Technology Austria GmbH Durisolstrasse 2 A-4600 Wels Austria Tel: 43-7242-2244-399 Fax: 43-7242-2244-393

### Denmark

Microchip Technology Nordic ApS Regus Business Centre Lautrup hoj 1-3 Ballerup DK-2750 Denmark Tel: 45 4420 9895 Fax: 45 4420 9910

### France

Microchip Technology SARL Parc d'Activite du Moulin de Massy 43 Rue du Saule Trapu Batiment A - ler Etage 91300 Massy, France Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

### Germany

Microchip Technology GmbH Steinheilstrasse 10 D-85737 Ismaning, Germany Tel: 49-89-627-144 0 Fax: 49-89-627-144-44

Microchip Technology SRL Centro Direzionale Colleoni Palazzo Taurus 1 V. Le Colleoni 1 20041 Agrate Brianza Milan, Italy
Tel: 39-039-65791-1 Fax: 39-039-6899883

#### **United Kingdom**

Microchip Ltd. 505 Eskdale Road Winnersh Triangle Wokingham Berkshire, England RG41 5TU Tel: 44 118 921 5869 Fax: 44-118 921-5820

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